

SPECIFICATION

Product : 3mm Infra-Red Dome Lamp

Part No. : IWL-SI3R30F-XXX

Date : 2013. 07. 26 Ver. 3.0

Proposed By	Checked By	Checked By	Checked By	Checked By	Approval
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Comment



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3mm Dome LED Lamp

IWL-SI3R30F-XXX



1. Features

- Round Type Lamp
- 3mm Resin Mold Type
- Colored Infra-Red
- Transparency, Diffused or Colored Lens Type
- High Luminous Intensity
- Chip Material Based GaN

2. Applications

- IR Communication
- Emitting Sensor
- Detector

3. Outline Drawing and Dimension

* Unit : mm, Tolerance : ± 0.5

Front View		Side View	Top View
With Stopper	Without Stopper		
			<p>Circuit Diagram</p> <p>① Cathode Anode ②</p>

* Note

1. All dimensions are in millimeters
2. All dimensions without tolerances are for reference only
3. Base Material : Fe Alloy
4. Molding : Epoxy
5. Lead Plating : Ag/Ni
6. Pb Free

4. Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Value	Unit
Power Dissipation	P_d	180	mW
Continuous Forward Current	I_F	100	mA
Peak Forward Current ^{*1}	I_{FP}	1000	mA
Operating Temperature	T_{opr}	-30 ~ 85	°C
Storage Temperature	T_{stg}	-40 ~ 100	°C
Soldering Temperature	T_{sol}	260 (5sec)	°C

^{*1} Duty ratio = 1/10, Pulse width = 10ms

5. Electrical & Optical Characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Forward Voltage ^{*2}	V_F	$I_F = 20 \text{ mA}$	1.2	-	1.8	V
Reverse Current	I_R	$V_R = 5 \text{ V}$	-	-	10	μA
Radiant Intensity ^{*3}	I_e	$I_F = 20 \text{ mA}$	1	-	10	mW/sr
Peak Wavelength ^{*4}	W_P	$I_F = 20 \text{ mA}$	760	-	780	nm
Viewing angle ^{*5}	$2\theta_{1/2}$	$I_F = 20 \text{ mA}$	-	30	-	deg.

^{*2} Forward Voltage has a tolerance of $\pm 0.05 \text{ V}$.

^{*3} Radiant Intensity is measured with an integrating sphere and has an accuracy of 10%.

^{*4} Peak Wavelength has an accuracy of $\pm 2 \text{ nm}$

^{*5} Viewing Angle is the angle until 50% of brightness measured from the front part of LED.

5.1 Radiant Intensity Rank

Rank	Radiant Intensity (mW/sr)
0	1 ~ 8
1	8 ~ 10

5.2 Forward Voltage Rank

Rank	Forward Voltage (V)
0	1.2 ~ 1.8

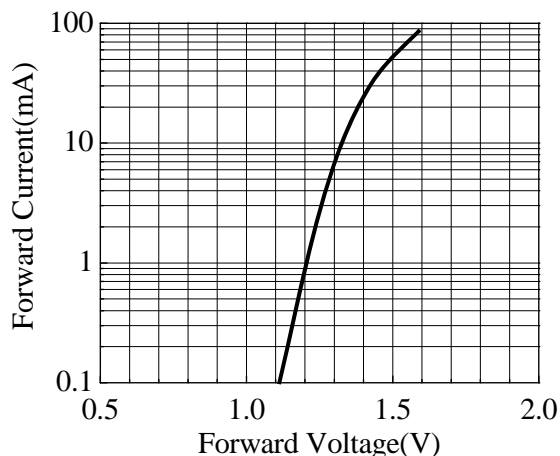
5.3 Peak Wavelength Rank

Rank	Peak Wavelength (nm)
B	760 ~ 780

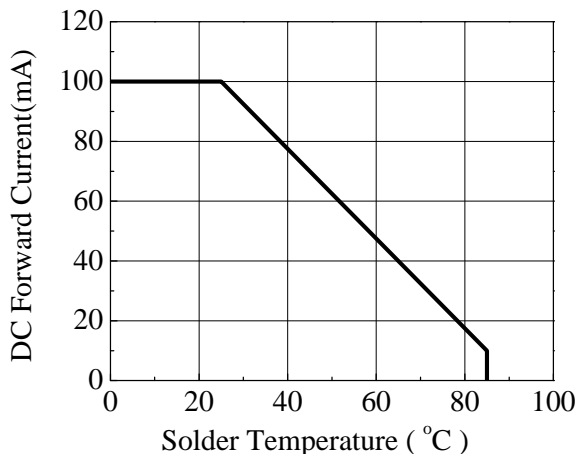
6. Typical Characteristic Curve

Forward Current vs. Forward Voltage

$T_a=25^{\circ}\text{C}$

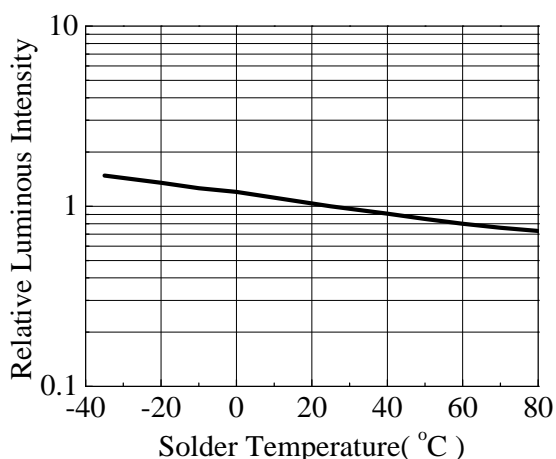


Forward Current vs. Solder Temperature



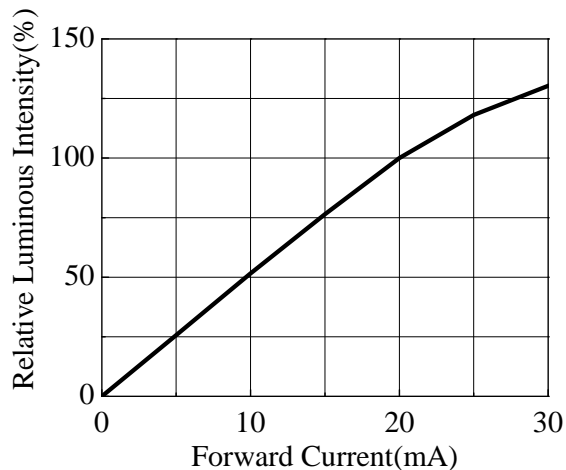
Relative Luminous Intensity vs. Solder Temperature

$I_f=20\text{mA}$



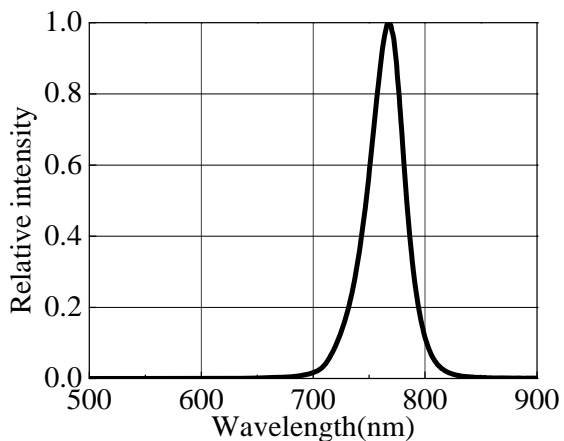
Relative Luminous Intensity vs. Forward Current

$T_a=25^{\circ}\text{C}$



Relative Luminous Intensity vs. Wavelength

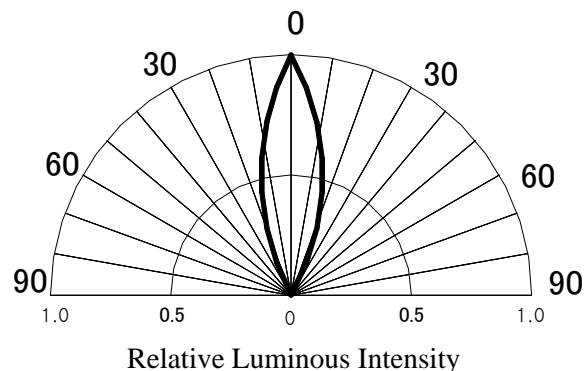
$T_a=25^{\circ}\text{C}$
 $I_f=20\text{mA}$



Radiation Diagram

$T_a=25^{\circ}\text{C}$
 $I_f=20\text{mA}$

- Viewing Angle : 30°



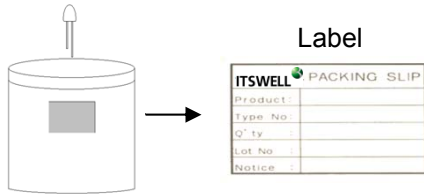
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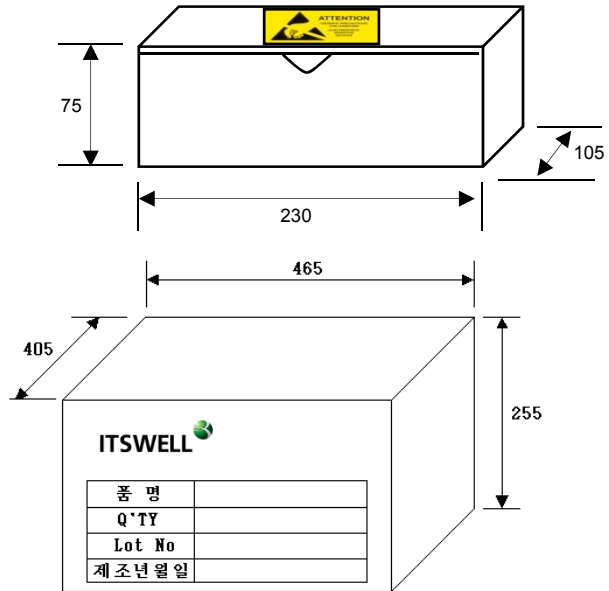
7. Packing & Tapping Dimension

7.1 Bulk Packing

- Bag packing



- Inner Box

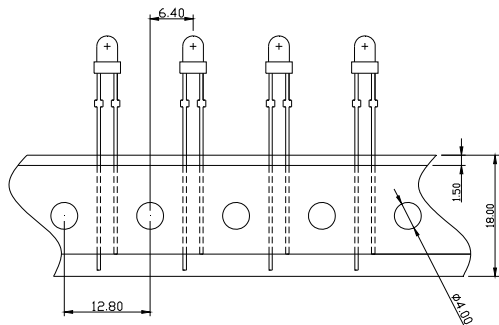


- Out Packing

- Maximum Inner Box 20 / 1 Box
40,000 pcs/ 1 Box
- Out box material : Carton

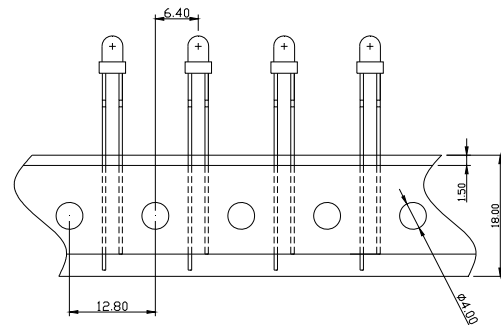
7.2 Tapping Packing

- With Stopper



* Unit : mm, Tolerance : ± 0.5

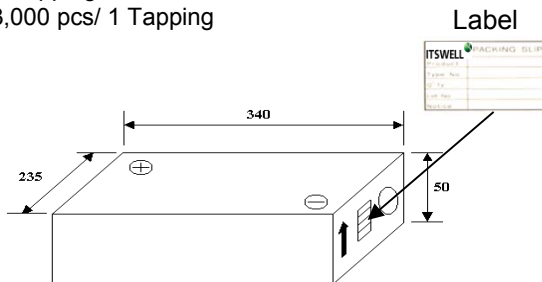
- Without Stopper



* Unit : mm, Tolerance : ± 0.5

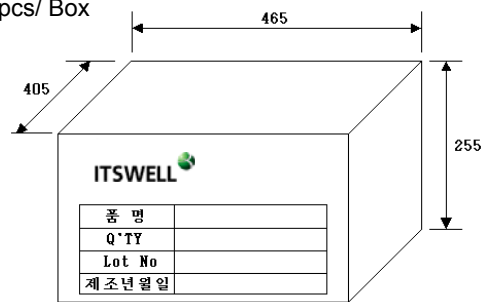
- Taping Box

- Tapping Box (Carton)
- 1 Tapping Box / Pack with Silica Gel
- 3,000 pcs/ 1 Tapping



- Out Box

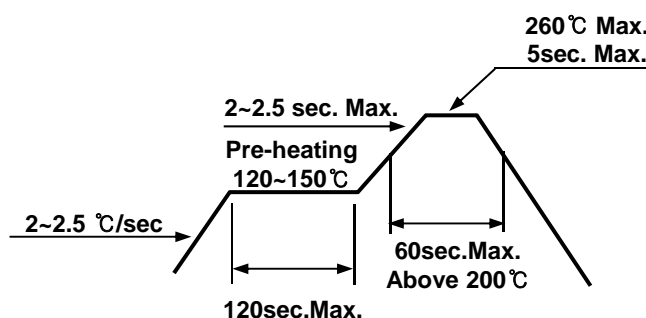
- Maximum 10 Tapping Box / Box
- 30,000 pcs/ Box



8. Precaution in use

8.1 Soldering Conditions

- When soldering DIP LED , Heat may affect the electrical and optical characteristics of the LEDs.
- In soldering, do not stress the lead frame and the resin part under the high temperature.
- The epoxy part should be protected from mechanical stress or vibration until the DIP LEDs return to room temperature after soldering.
- Preliminary heating to be at 120~150°C max. for 120 Seconds max.
- Soldering heat to be at 260°C max. for 5sec. Max.
- For manual Soldering is Not more than 3sec @MAX350°C , under soldering iron



8.2 Storage

- Use within 7 days after opening packing. Store in 10 to 30 °C. DIP LED lead frames are plated Silver. The silver surface may be affected by environment which contain corrosive gases and so on. Please avoid condition which may cause the DIP LED to corroded, tarnish or discolor.

8.3 Static Electricity

- Static electricity or surge voltage damages the DIP LEDs. It is recommended that a wrist band or an anti-electrostatic glove be used when handling the LEDs.
- A tip soldering iron is requested to be grounded. An ionizer should also be installed where risk of static.
- All devices, equipment and machinery must be properly grounded (via 1MΩ). It is recommended that measures be taken against surge voltage to the equipment that mounts the DIP LEDs.

8.4 Cleaning

- Isopropyl Alcohol or Ethylene Alcohol is recommended in 5 minutes at room temperature. Don't use unspecified chemical may cause crack or haze on the surface of the epoxy resin.
- Before cleaning, a pre-test should be done to confirm whether any damage to the DIP LED will occur.
- Freon solvents should not be used to clean the DIP LEDs because of worldwide regulations.

9. Reliability

9.1 Reliability Test Item

Test Items	Test Conditions	Notes
High Temperature Storage	100°C, 1,000hr.	0/20
Low Temperature Storage	-40°C, 1,000hr.	0/20
Temp. Humidity Storage	60°C, 90% RH, 1,000hr.	0/20
Steady State Operating life	25°C, 30mA , 1,000hr.	0/20
High Temperature Operating Life	85°C, 10mA, 1,000hr.	0/20
Low Temperature Operating Life	-30°C, 20mA, 1,000hr.	0/20
Steady State Operating life Of High Humidity Heat	60°C, 90% RH, 15mA, 1,000hr.	0/20
Thermal Shock	-40°C (30min) ↔ 100°C (30min.), 100 cycle	0/20
ESD	HBM, 100 pF, 1.5 kΩ, 3 times	0/20

9.2 Criteria for Judging the Damage

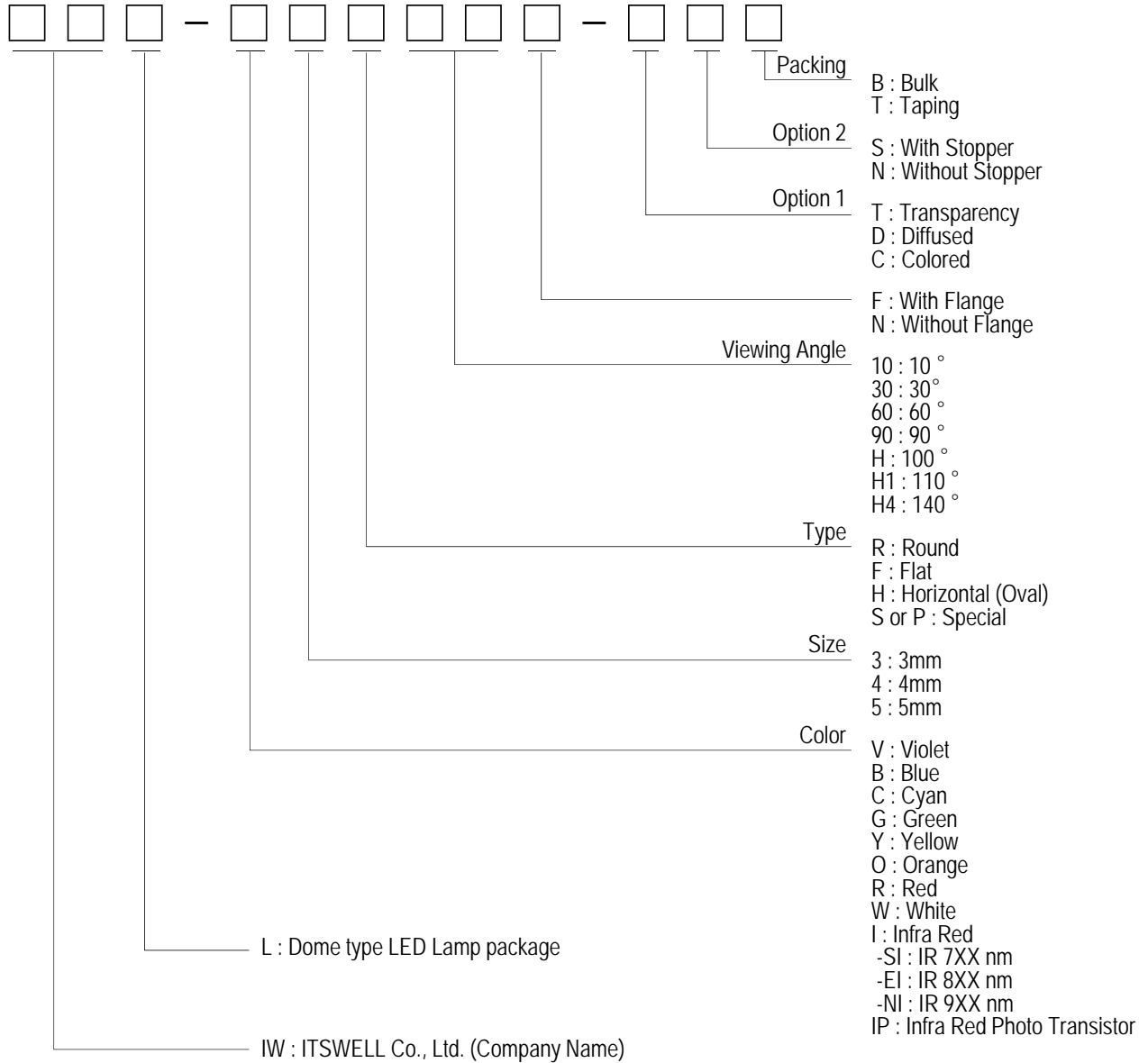
Items	Test Conditions	Criteria for judgment
Radiant Intensity (I_e)	$I_F = 20\text{mA}$	> 70% of S
Forward Voltage (V_F)	$I_F = 20\text{mA}$	Less than 110% of U

* U means the upper limit of specified characteristics, S means initial value.

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10. Part Name Description



11. Attention : Electric Static Discharge (ESD) Protection



The symbol shown on the page herein to introduce 'Electro-Optical Characteristics'. ESD protection for GaP and AlGaAs based chips is still necessary even though they are safe in low static-electric discharge. Material in AlInGaP, GaP, or/and InGaN based chips are STATIC SENSITIVE devices. ESD protection has to be considered and taken in the initial design stage. If manual work/process is needed, please ensure the device is well protected from ESD during all the process.

■ Spec. Review History

Review Ver.	Date	Correction List	Etc.
Ver 1.0	2006.06.19	Establish	
Ver 2.0	2012.01.16	Changed Part Name	
Ver 3.0	2013.07.26	Revision	